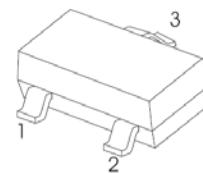


General Description

These devices are particularly suited for low voltage applications in notebook computers, portable phones, PCMCIA cards, and other battery powered circuits where fast switching, and low in-line power loss are needed in a very small outline surface mount package.

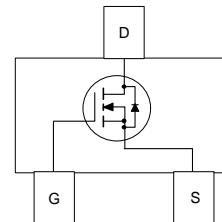
SOT - 23



1. GATE
2. SOURCE
3. DRAIN

Features

- V_{DS} (V) = 30V
- I_D = 2.2A (V_{GS} =4.5V)
- $R_{DS(ON)}$ < 65mΩ (V_{GS} = 4.5V)
- $R_{DS(ON)}$ < 82mΩ (V_{GS} = 2.5V)
- High density cell design for extremely low $R_{DS(ON)}$.
- Exceptional on-resistance and maximum DC current capability.



Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | FDN337N | Units |
|-------------------------|---|------------|-------|
| V_{DSS} | Drain-Source Voltage | 30 | V |
| V_{GSS} | Gate-Source Voltage - Continuous | ± 8 | V |
| I_D | Drain/Output Current - Continuous | 2.2 | A |
| | - Pulsed | 10 | |
| P_D | Maximum Power Dissipation (Note 1a) | 0.5 | W |
| | (Note 1b) | 0.46 | |
| T_J, T_{STG} | Operating and Storage Temperature Range | -55 to 150 | °C |
| THERMAL CHARACTERISTICS | | | |
| R_{JA} | Thermal Resistance, Junction-to-Ambient (Note 1a) | 250 | °C/W |
| R_{JC} | Thermal Resistance, Junction-to-Case (Note 1) | 75 | °C/W |

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---|---|--|-----|------|------------------|----------------------------|
| OFF CHARACTERISTICS | | | | | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{\text{GS}} = 0 \text{ V}$, $I_D = 250 \mu\text{A}$ | 30 | | | V |
| $\Delta \text{BV}_{\text{DSS}}/\Delta T_J$ | Breakdown Voltage Temp. Coefficient | $I_D = 250 \mu\text{A}$, Referenced to 25°C | | 41 | | $\text{mV}/^\circ\text{C}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{\text{DS}} = 24 \text{ V}$, $V_{\text{GS}} = 0 \text{ V}$ $T_J = 55^\circ\text{C}$ | | 1 | $10 \mu\text{A}$ | μA |
| I_{GSSF} | Gate - Body Leakage, Forward | $V_{\text{GS}} = 8 \text{ V}$, $V_{\text{DS}} = 0 \text{ V}$ | | 100 | nA | |
| I_{GSSR} | Gate - Body Leakage, Reverse | $V_{\text{GS}} = -8 \text{ V}$, $V_{\text{DS}} = 0 \text{ V}$ | | -100 | nA | |
| ON CHARACTERISTICS (Note) | | | | | | |
| $V_{\text{GS(th)}}$ | Gate Threshold Voltage | $V_{\text{DS}} = V_{\text{GS}}$, $I_D = 250 \mu\text{A}$ | 0.4 | 0.7 | 1 | V |
| $\Delta V_{\text{GS(th)}}/\Delta T_J$ | Gate Threshold Voltage Temp. Coefficient | $I_D = 250 \mu\text{A}$, Referenced to 25°C | | -2.3 | | $\text{mV}/^\circ\text{C}$ |
| $R_{\text{DS(ON)}}$ | Static Drain-Source On-Resistance | $V_{\text{GS}} = 4.5 \text{ V}$, $I_D = 2.2 \text{ A}$ | | 54 | 65 | $\text{m}\Omega$ |
| | | $V_{\text{GS}} = 2.5 \text{ V}$, $I_D = 2 \text{ A}$ | | 70 | 82 | |
| $I_{\text{D(ON)}}$ | On-State Drain Current | $V_{\text{GS}} = 4.5 \text{ V}$, $V_{\text{DS}} = 5 \text{ V}$ | 10 | | | A |
| g_{FS} | Forward Transconductance | $V_{\text{DS}} = 5 \text{ V}$, $I_D = 2.2 \text{ A}$ | | 13 | | S |
| DYNAMIC CHARACTERISTICS | | | | | | |
| C_{iss} | Input Capacitance | $V_{\text{DS}} = 10 \text{ V}$, $V_{\text{GS}} = 0 \text{ V}$, $f = 1.0 \text{ MHz}$ | | 300 | | pF |
| C_{oss} | Output Capacitance | | | 145 | | pF |
| C_{rss} | Reverse Transfer Capacitance | | | 35 | | pF |
| SWITCHING CHARACTERISTICS (Note) | | | | | | |
| $t_{\text{D(on)}}$ | Turn - On Delay Time | $V_{\text{DD}} = 5 \text{ V}$, $I_D = 1 \text{ A}$, $V_{\text{GS}} = 4.5 \text{ V}$, $R_{\text{GEN}} = 6 \Omega$ | | 4 | 10 | ns |
| t_r | Turn - On Rise Time | | | 10 | 18 | ns |
| $t_{\text{D(off)}}$ | Turn - Off Delay Time | | | 17 | 28 | ns |
| t_f | Turn - Off Fall Time | | | 4 | 10 | ns |
| Q_g | Total Gate Charge | $V_{\text{DS}} = 10 \text{ V}$, $I_D = 2.2 \text{ A}$, $V_{\text{GS}} = 4.5 \text{ V}$ | | 7 | 9 | nC |
| Q_{gs} | Gate-Source Charge | | | 1.1 | | nC |
| Q_{gd} | Gate-Drain Charge | | | 1.9 | | nC |
| DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS | | | | | | |
| I_s | Maximum Continuous Drain-Source Diode Forward Current | | | | 0.42 | A |
| V_{SD} | Drain-Source Diode Forward Voltage | $V_{\text{GS}} = 0 \text{ V}$, $I_s = 0.42 \text{ A}$ (Note) | | 0.65 | 1.2 | V |

Note:

1. R_{BA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BA} is guaranteed by design while R_{BCA} is determined by the user's board design.

Typical R_{BA} using the board layouts shown below on FR-4 PCB in a still air environment :

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$.



a. $250^\circ\text{C}/\text{W}$ when mounted on 0.02 in² pad of 2oz Cu.



b. $270^\circ\text{C}/\text{W}$ when mounted on a 0.001 in² pad of 2oz Cu.

Typical Electrical Characteristics

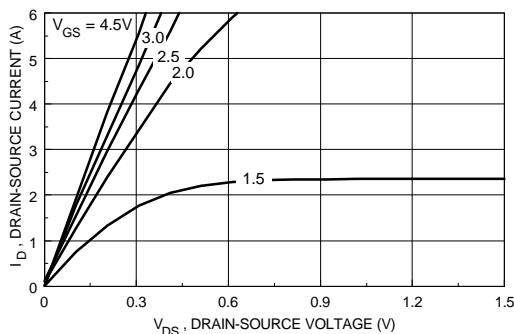


Figure 1. On-Region Characteristics.

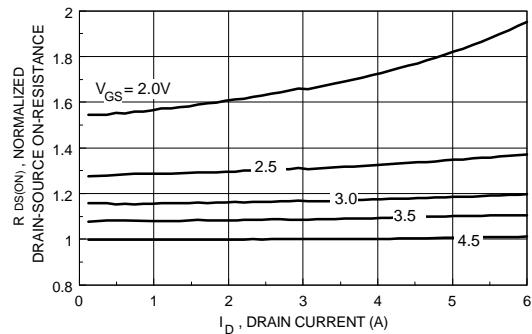


Figure 2. On-Resistance Variation with Drain Current and Gate

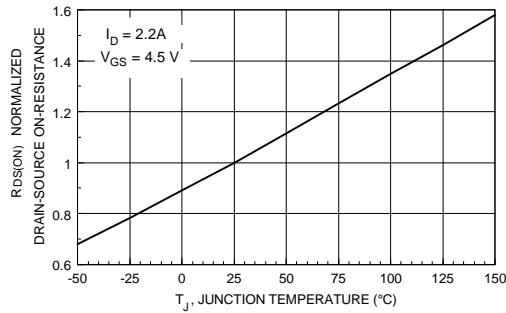


Figure 3. On-Resistance Variation with Temperature.

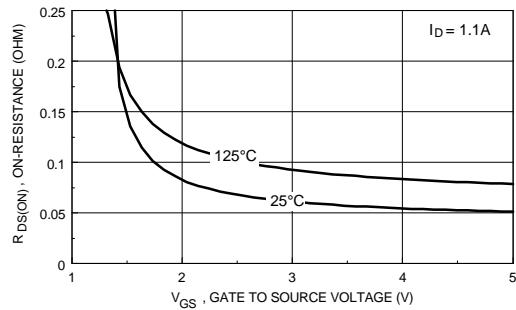


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

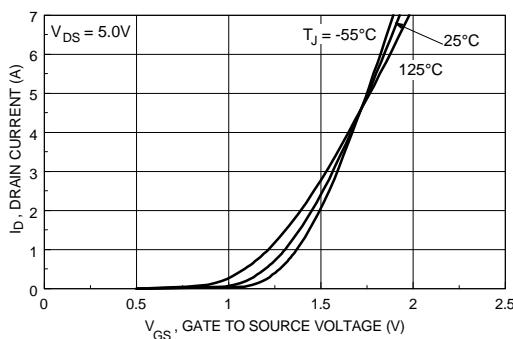
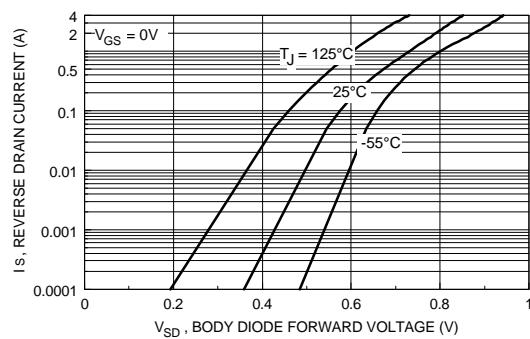


Figure 5. Transfer Characteristics.



Typical Electrical Characteristics (continued)

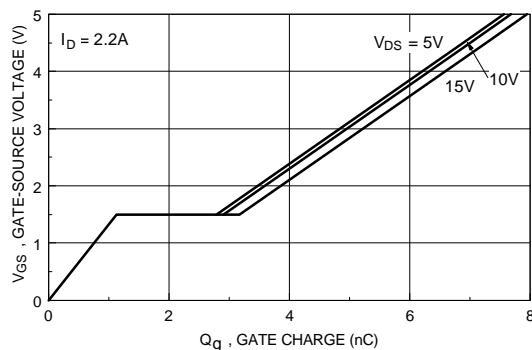


Figure 7. Gate Charge Characteristics.

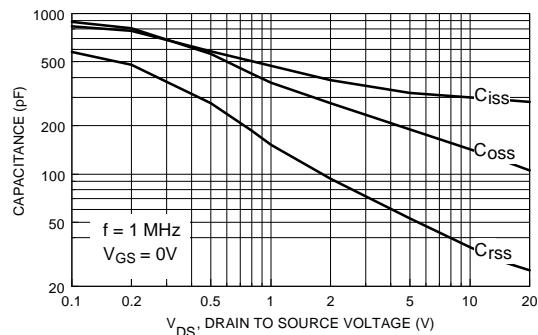


Figure 8. Capacitance Characteristics.

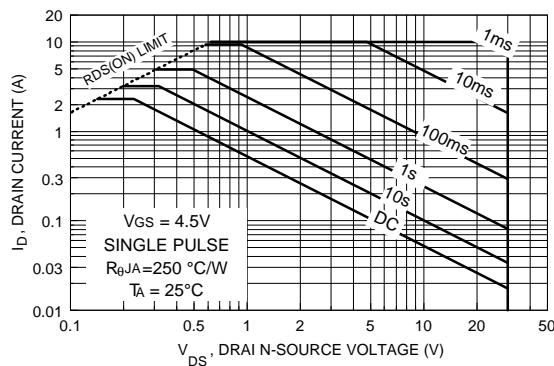


Figure 9. Maximum Safe Operating Area.

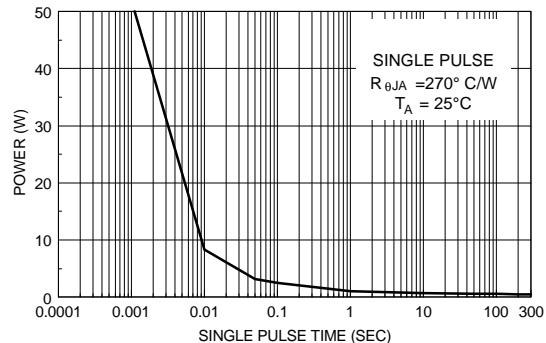


Figure 10. Single Pulse Maximum Power Dissipation.

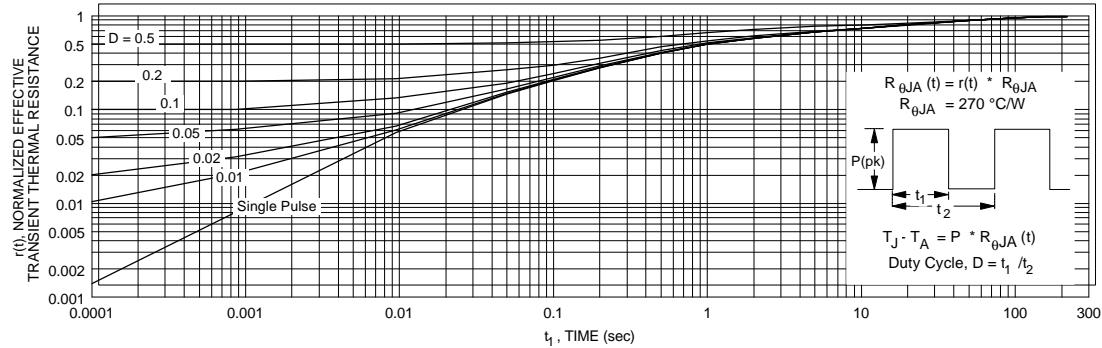
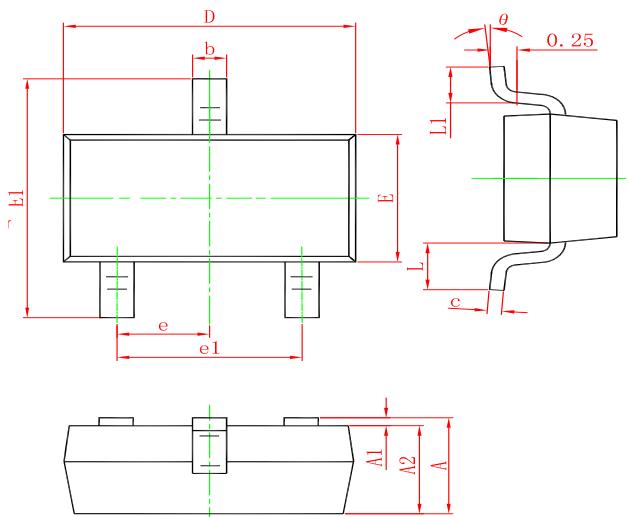


Figure 11. Transient Thermal Response Curve.

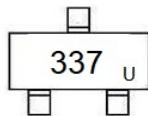
Thermal characterization performed using the conditions described in note 1b.
Transient thermal response will change depending on the circuit board design.

SOT-23 PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950 TYP. | | 0.037 TYP. | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550 REF. | | 0.022 REF. | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 |
| θ | 0° | 8° | 0° | 8° |

Marking



Ordering information

| Order code | Package | Baseqty | Deliverymode |
|------------|---------|---------|---------------|
| FDN337N | SOT-23 | 3000 | Tape and reel |